



Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	0.8	A
V_{DRM}/V_{RRM}	400, 600, or 800	V
I_{GT}	5 to 200	μA

Applications

The SxX8xSx EV series is specifically designed for GFCI (Ground Fault Circuit Interrupter) and gas ignition applications.

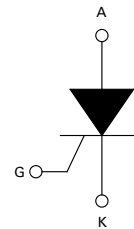
Description

This new component series offers high static dv/dt and low turn off time (t_q) sensitive SCR with its small die planar construction design. It is specifically designed for GFCI (Ground Fault Circuit Interrupter) and Gas Ignition applications. All SCRs junctions are glass-passivated to ensure long term reliability and parametric stability.

Features

- RoHS compliant and Halogen-Free
- Thru-hole and surface mount packages
- Surge current capability > 10Amps
- Blocking voltage (V_{DRM}/V_{RRM}) capability - up to 800V
- High dv/dt noise immunity
- Improved turn-off time (t_q) < 25 μsec
- Sensitive gate for direct microprocessor interface

Schematic Symbol



Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	TO-92 $T_c = 55^\circ C$	0.8 A
		SOT-89 $T_c = 60^\circ C$	0.8 A
		SOT-223 $T_L = 60^\circ C$	0.8 A
$I_{T(AV)}$	Average on-state current	TO-92 $T_c = 55^\circ C$	0.51 A
		SOT-89 $T_c = 60^\circ C$	0.51 A
		SOT-223 $T_L = 60^\circ C$	0.51 A
I_{TSM}	Non repetitive surge peak on-state current (Single cycle, T_j initial = 25°C)	TO-92 $F = 50Hz$	8 A
		SOT-89 $F = 60Hz$ SOT-223	10 A
I^2t	I^2t Value for fusing	$t_p = 10$ ms $F = 50$ Hz	0.32 A^2s
		$t_p = 8.3$ ms $F = 60$ Hz	0.41 A^2s
di/dt	Critical rate of rise of on-state current $I_g = 10mA$	TO-92 $T_j = 125^\circ C$ SOT-89 SOT-223	50 $A/\mu s$
I_{GM}	Peak Gate Current	$t_p = 10$ μs $T_j = 125^\circ C$	1.0 A
$P_{G(AV)}$	Average gate power dissipation	$T_j = 125^\circ C$	0.1 W
T_{stg}	Storage junction temperature range	—	-40 to 150 $^\circ C$
T_j	Operating junction temperature range	—	-40 to 125 $^\circ C$

Electrical Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Description	Test Conditions	Limit	Value			Unit
				SxX8yS1	SxX8yS2	SxX8yS	
I _{GT}	DC Gate Trigger Current	V _D = 6V R _L = 100 Ω	MIN.	0.5	1	15	μA
			MAX.	5	50	200	μA
V _{GT}	DC Gate Trigger Voltage	V _D = 6V R _L = 100 Ω	MAX.	0.8			V
V _{GRM}	Peak Reverse Gate Voltage	I _{RG} = 10μA	MIN.	5			V
I _H	Holding Current	R _{GK} = 1 kΩ Initial Current = 20mA	MAX.	5			mA
(dv/dt) _s	Critical Rate-of-Rise of Off-State Voltage	T _J = 125°C V _D = V _{DRM} / N _{RRM} Exp. Waveform R _{GK} = 1 kΩ	MIN.	75			V/μs
V _{GD}	Gate Non-Trigger Voltage	V _D = V _{DRM} R _{GK} = 1 kΩ T _J = 125°C	MIN.	0.2			V
t _q	Turn-Off Time	T _J = 25°C @ 600 V R _{GK} = 1 kΩ	MAX.	30	25	25	μs
t _{gt}	Turn-On Time	I _G = 10mA PW = 15μsec I _T = 1.6A(pk)	TYP.	2.0	2.0	2.0	μs

Note: x = voltage/100, y = package

Static Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Description	Test Conditions	Limit	Value	Unit
V _{TM}	Peak On-State Voltage	I _{TM} = 1.6A (pk)	MAX.	1.70	V
I _{DRM}	Off-State Current, Peak Repetitive	T _J = 25°C @ V _D = V _{DRM} R _{GK} = 1 kΩ	MAX.	3	μA
		T _J = 125°C @ V _D = V _{DRM} R _{GK} = 1 kΩ	MAX.	500	μA

Thermal Resistances

Symbol	Description	Test Conditions	Value	Unit	
R _{θJC}	Junction to case (AC)	I _T = 0.8A _(RMS) ¹	TO-92	75	°C/W
			SOT-223	30	°C/W
			SOT-89	50	°C/W
R _{θJA}	Junction to ambient	I _T = 0.8A _(RMS) ¹	TO-92	150	°C/W
			SOT-223	60	°C/W
			SOT-89	90	°C/W

¹ 60Hz AC resistive load condition, 100% conduction.

Figure 1: Normalized DC Gate Trigger Current For All Quadrants vs. Junction Temperature

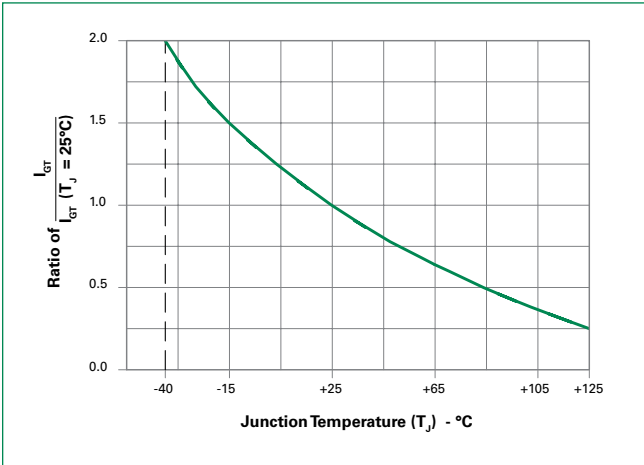


Figure 2: Normalized DC Holding Current vs. Junction Temperature

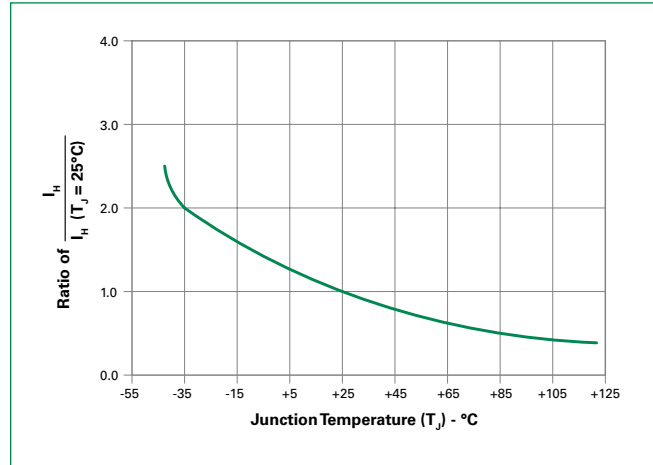


Figure 3: Normalized DC Gate Trigger Voltage vs. Junction Temperature

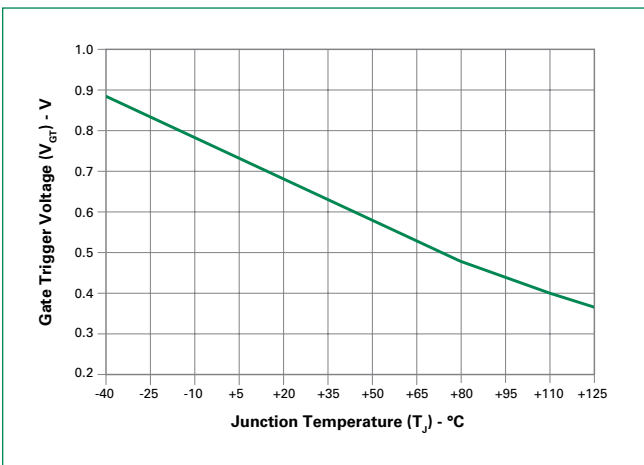


Figure 4: On-State Current vs. On-State Voltage (Typical)

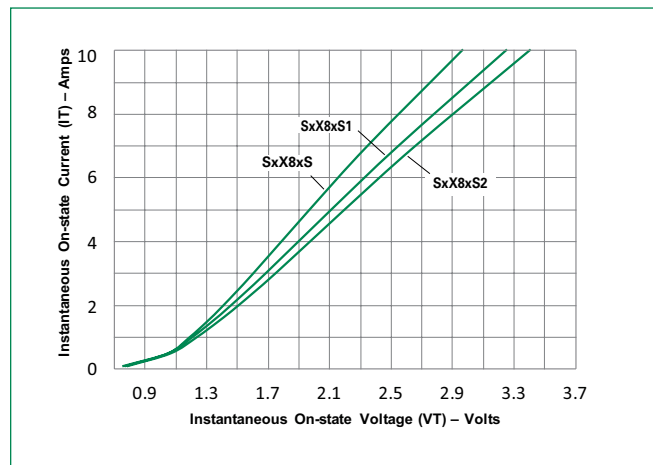


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

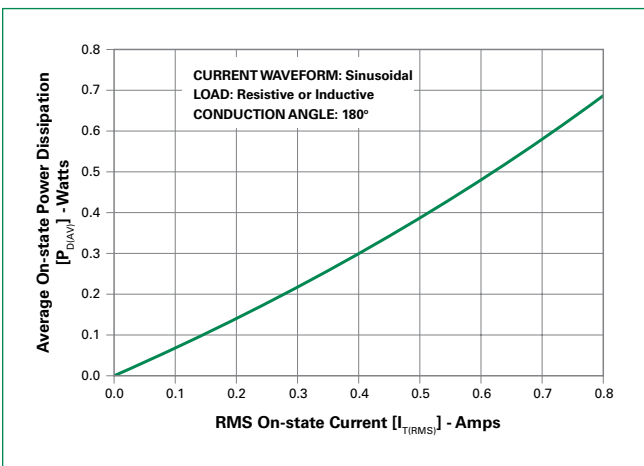


Figure 6: Maximum Allowable Case Temperature vs. On-State Current

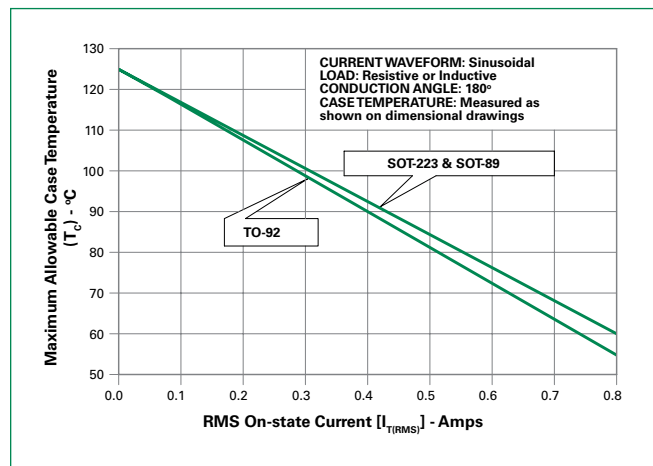


Figure 7-1: Typical DC Gate Trigger Current with R_{GK} vs. Junction Temperature for S6X8BS

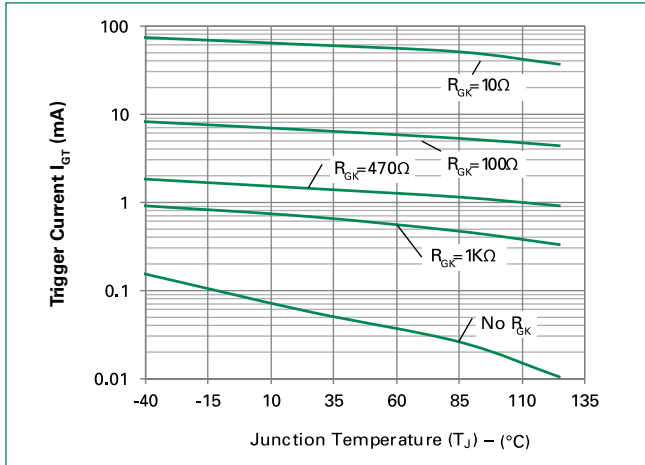


Figure 7-2: Typical DC Gate Trigger Current with R_{GK} vs. Junction Temperature for S8X8ESRP

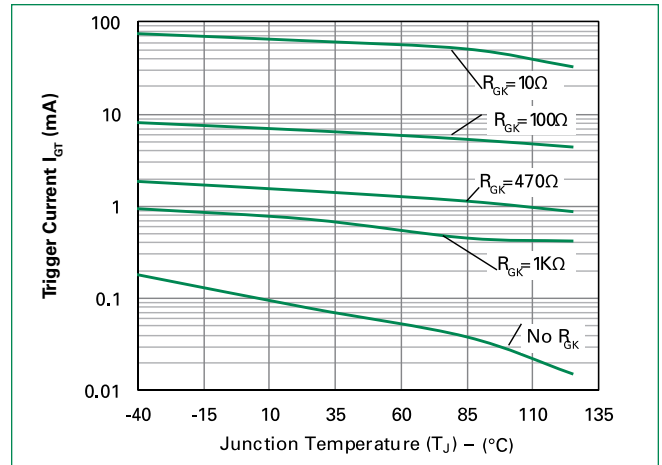


Figure 8-1: Typical DC Holding Current with R_{GK} vs. Junction Temperature for S6X8BS

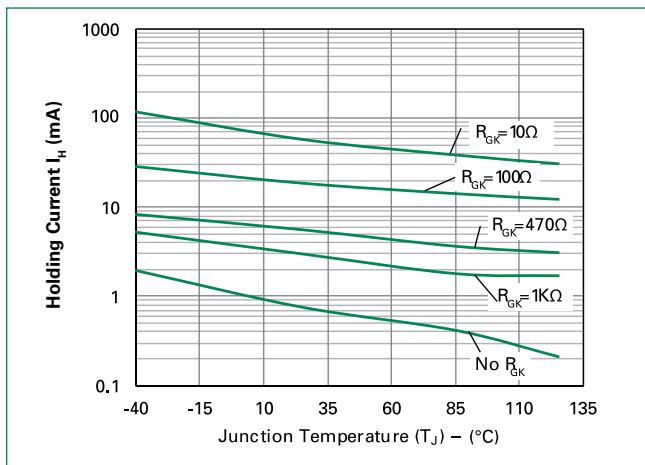


Figure 7-2: Typical DC Holding Current with R_{GK} vs. Junction Temperature for S8X8ESRP

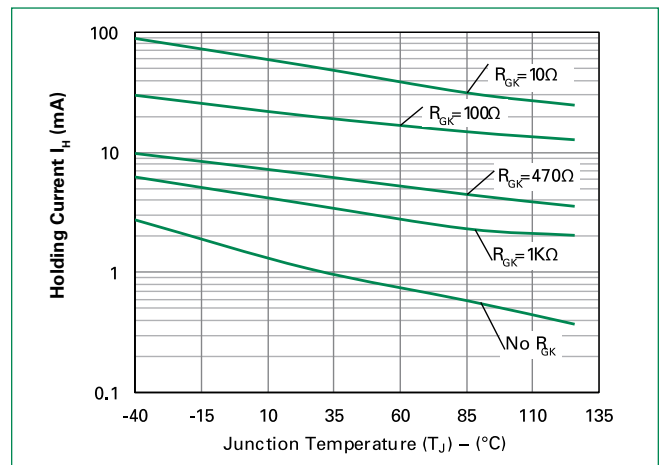


Figure 9-1: Typical DC Static dv/dt with R_{GK} vs. Junction Temperature for S6X8BS

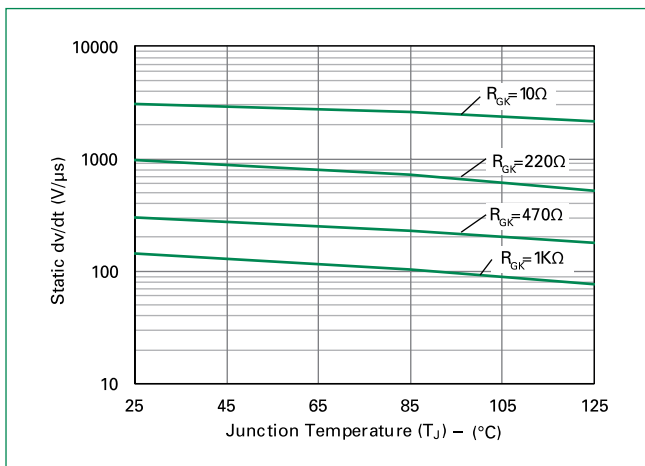


Figure 9-2: Typical DC Static dv/dt with R_{GK} vs. Junction Temperature for S8X8ESRP

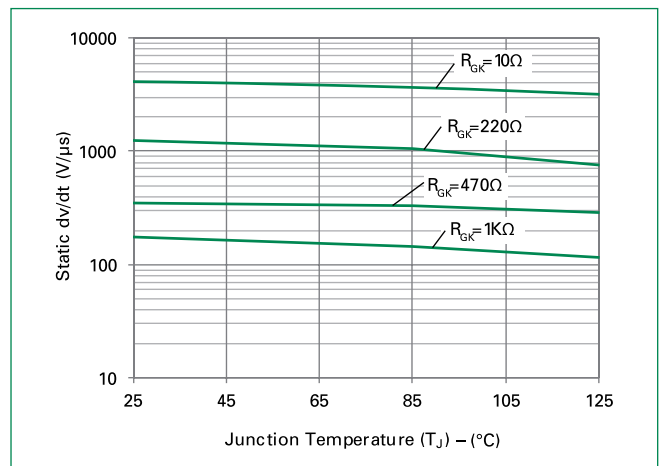


Figure 10-1: Typical DC turn off time with R_{GK} vs. Junction Temperature for S6X8BS

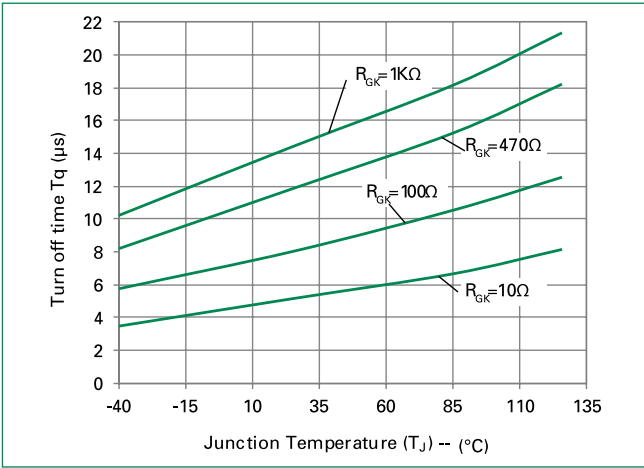


Figure 10-2: Typical DC turn off time with R_{GK} vs. Junction Temperature for S8X8ESRP

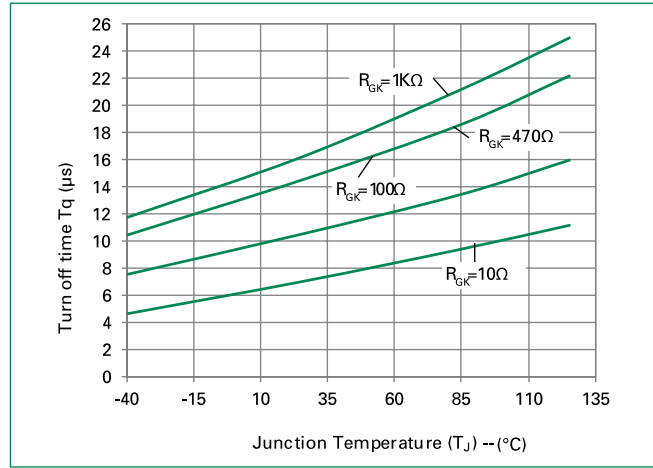
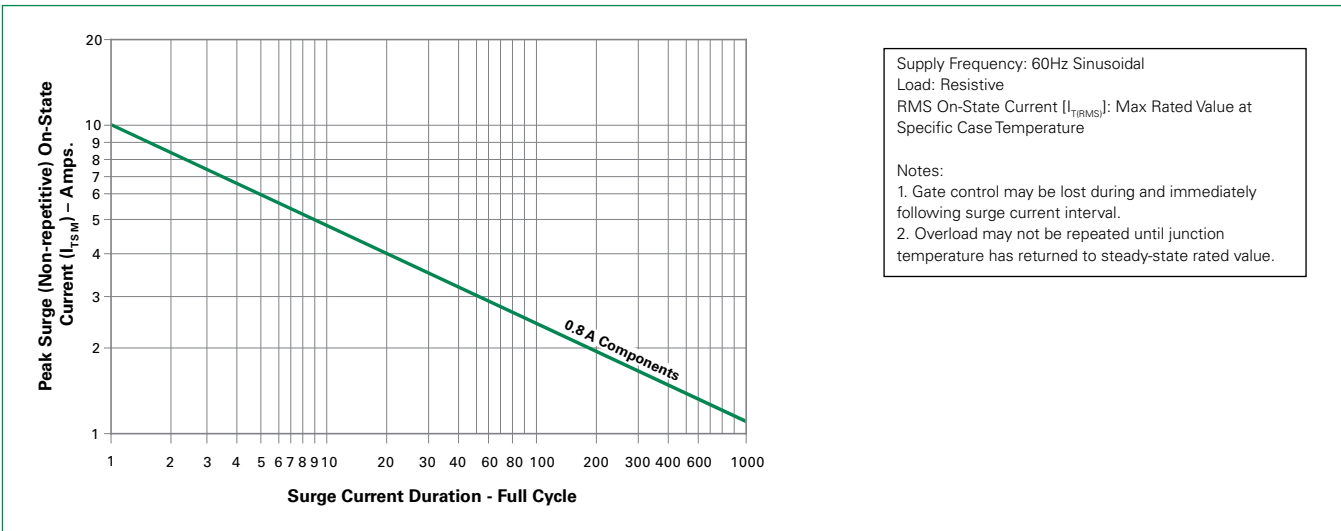
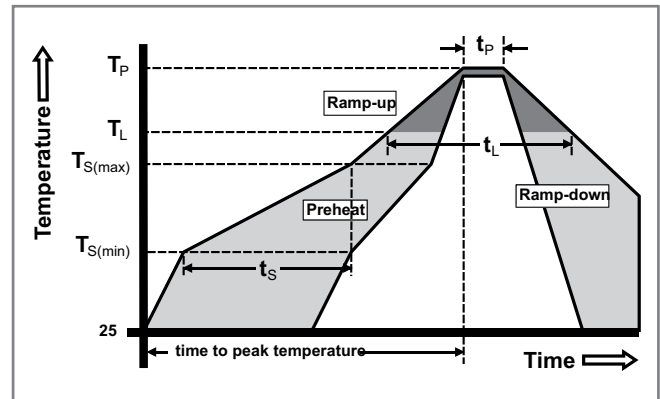


Figure 11: Surge Peak On-State Current vs. Number of Cycles



Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Time (min to max) (t_s)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		280°C



Additional Information



Datasheet



Resources



Samples

Physical Specifications

Terminal Finish	100% Matte Tin-plated.
Body Material	UL Recognized compound meeting flammability rating V-0
Lead Material	Copper Alloy

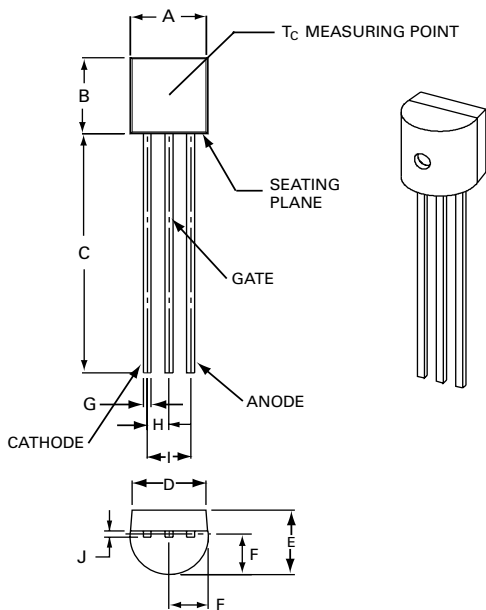
Design Considerations

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Reliability/Environmental Tests

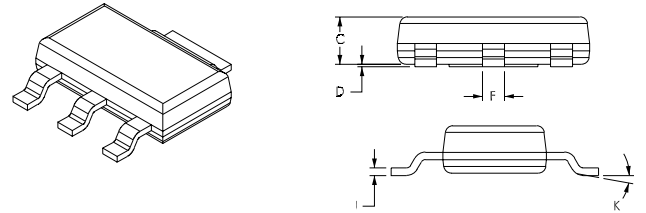
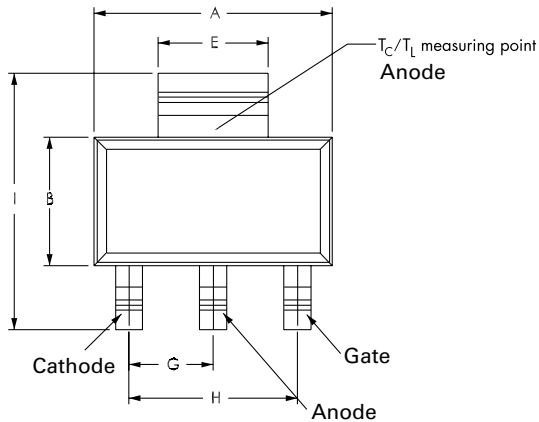
Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 110°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E

Dimensions – TO-92

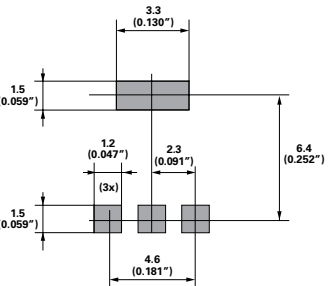


Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.175	0.205	4.450	5.200
B	0.170	0.210	4.320	5.330
C	0.500		12.70	
D	0.135		3.430	
E	0.125	0.165	3.180	4.190
F	0.080	0.105	2.040	2.660
G	0.016	0.021	0.407	0.533
H	0.045	0.055	1.150	1.390
I	0.095	0.105	2.420	2.660
J	0.015	0.020	0.380	0.500

Dimensions – SOT-223

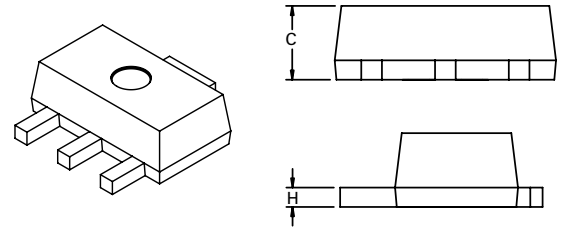
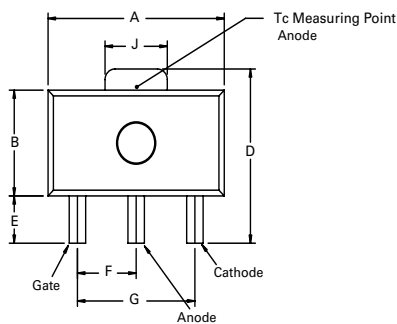


Dimensions	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.248	0.256	0.264	6.30	6.50	6.70
B	0.130	0.138	0.146	3.30	3.50	3.70
C	—	—	0.071	—	—	1.80
D	0.001	—	0.004	0.02	—	0.10
E	0.114	0.118	0.124	2.90	3.00	3.15
F	0.024	0.027	0.034	0.60	0.70	0.85
G	—	0.090	—	—	2.30	—
H	—	0.181	—	—	4.60	—
I	0.264	0.276	0.287	6.70	7.00	7.30
J	0.009	0.010	0.014	0.24	0.26	0.35
K	10° MAX					



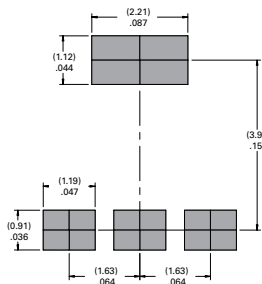
Dimensions in Millimeters (Inches)

Dimensions – SOT-89



Dimension	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.173	—	0.181	4.40	—	4.60
B	0.090	—	0.102	2.29	—	2.60
C	0.055	—	0.063	1.40	—	1.60
D	0.155	—	0.167	3.94	—	4.25
E	0.035	—	0.047	0.89	—	1.20
F	0.056	—	0.062	1.42	—	1.57
G	0.115	—	0.121	2.92	—	3.07
H	0.014	—	0.017	0.35	—	0.44
I	0.014	—	0.019	0.36	—	0.48
J	0.064	—	0.072	1.62	—	1.83

Pad Layout for SOT-89



Dimensions in Millimeters (Inches)

Product Selector

Part Number	Voltage			Gate Sensitivity	Package
	400V	600V	800V		
S4X8ES	X	—	—	200 μ A	TO-92
S6X8ES	—	X	—	200 μ A	TO-92
S8X8ES	—	—	X	200 μ A	TO-92
S4X8TS	X	—	—	200 μ A	SOT-223
S6X8TS	—	X	—	200 μ A	SOT-223
S8X8TS	—	—	X	200 μ A	SOT-223
S4X8BS	X	—	—	200 μ A	SOT-89
S6X8BS	—	X	—	200 μ A	SOT-89
S4X8ES1	X	—	—	5 μ A	TO-92
S6X8ES1	—	X	—	5 μ A	TO-92
S8X8ES1	—	—	X	5 μ A	TO-92
S4X8TS1	X	—	—	5 μ A	SOT-223
S6X8TS1	—	X	—	5 μ A	SOT-223
S8X8TS1	—	—	X	5 μ A	SOT-223
S4X8ES2	X	—	—	50 μ A	TO-92
S6X8ES2	—	X	—	50 μ A	TO-92
S8X8ES2	—	—	X	50 μ A	TO-92
S4X8TS2	X	—	—	50 μ A	SOT-223
S6X8TS2	—	X	—	50 μ A	SOT-223
S8X8TS2	—	—	X	50 μ A	SOT-223

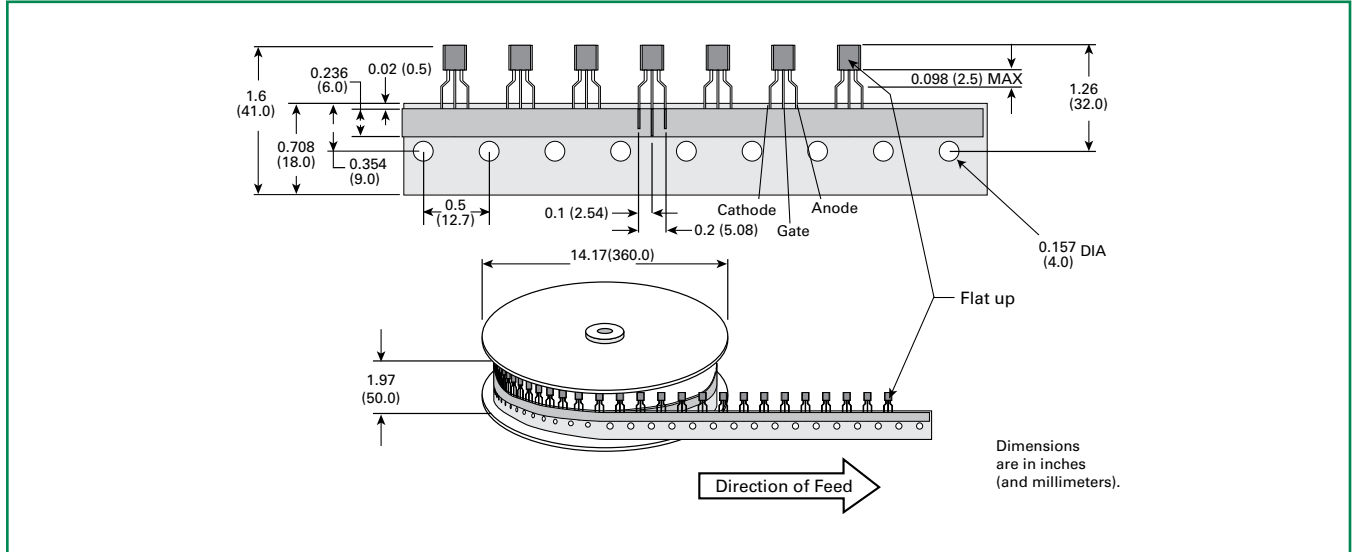
Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
SxX8ESy	SxX8ESy	0.217g	Bulk	2500
SxX8ESyAP	SxX8ESy	0.217g	Ammo Pack	2000
SxX8ESyRP	SxX8ESy	0.217g	Tape & Reel	2000
SxX8TSyRP	SxX8TSy	0.120g	Tape & Reel	1000
SxX8BSRP	xX8	0.053g	Tape & Reel	1000
SxX8BSRP1	xX8	0.053g	Tape & Reel	1000

Note: x = voltage/100, y = gate sensitivity

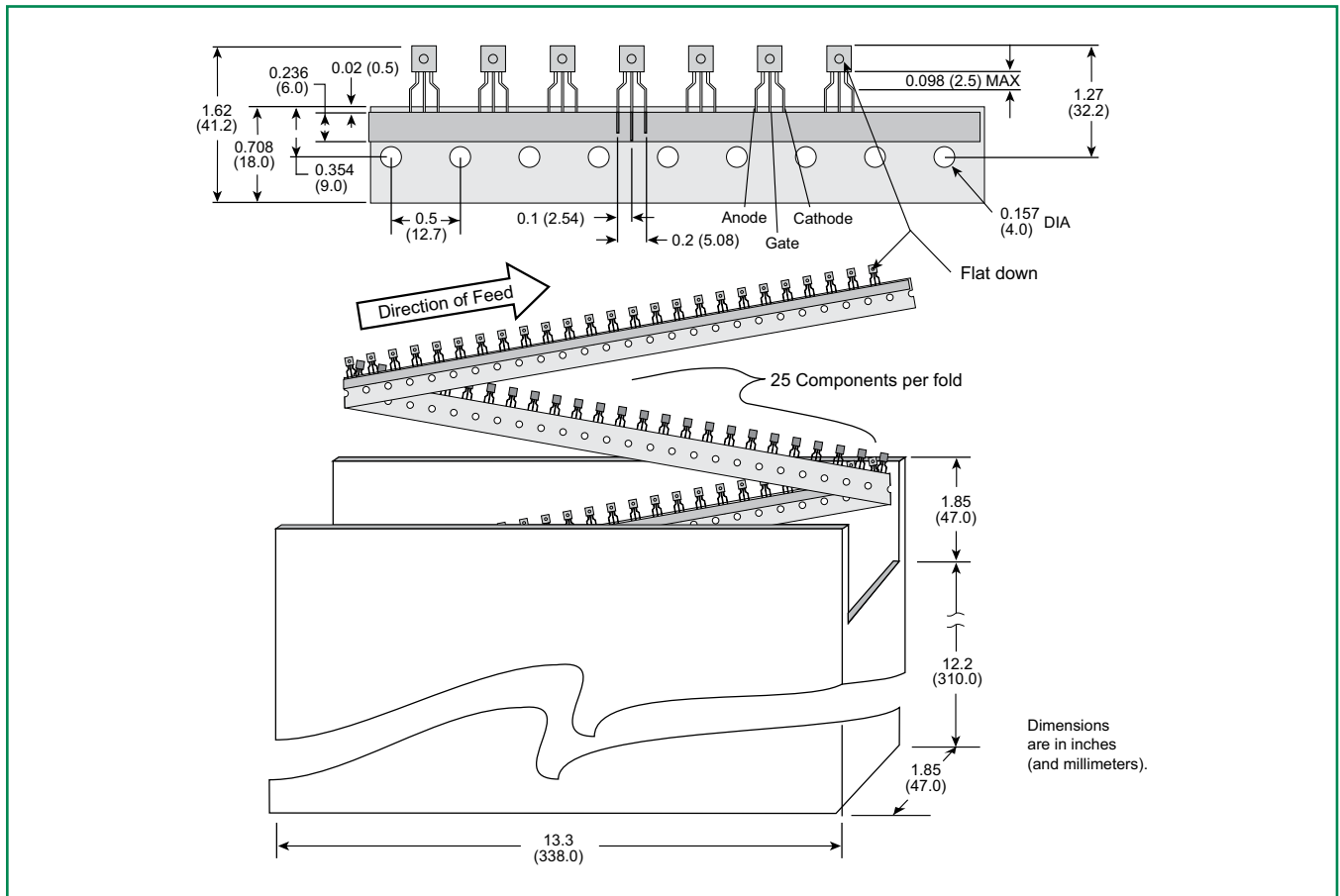
TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications

Meets all EIA-468-C Standards

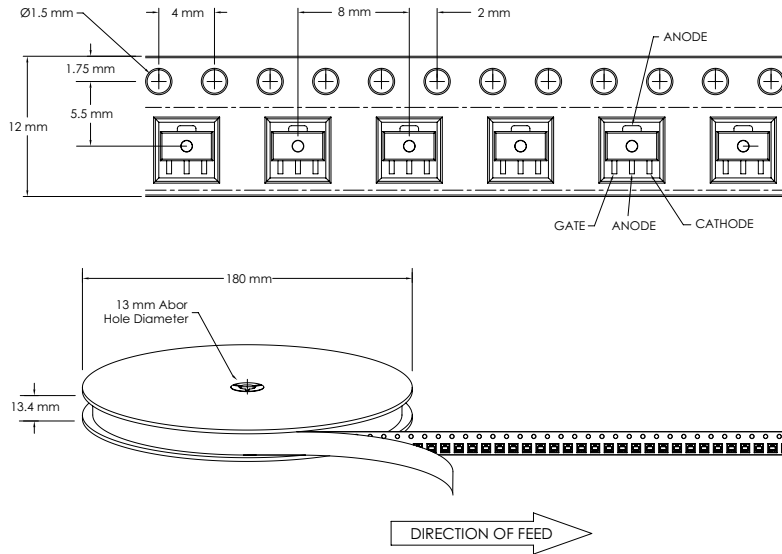


TO-92 (3-lead) Ammo Pack (AP) Radial Leaded Specifications

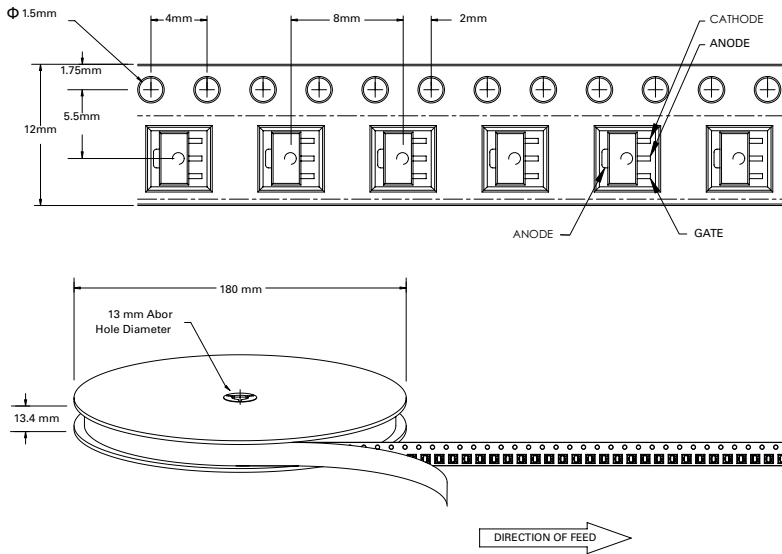
Meets all EIA-468-C Standards



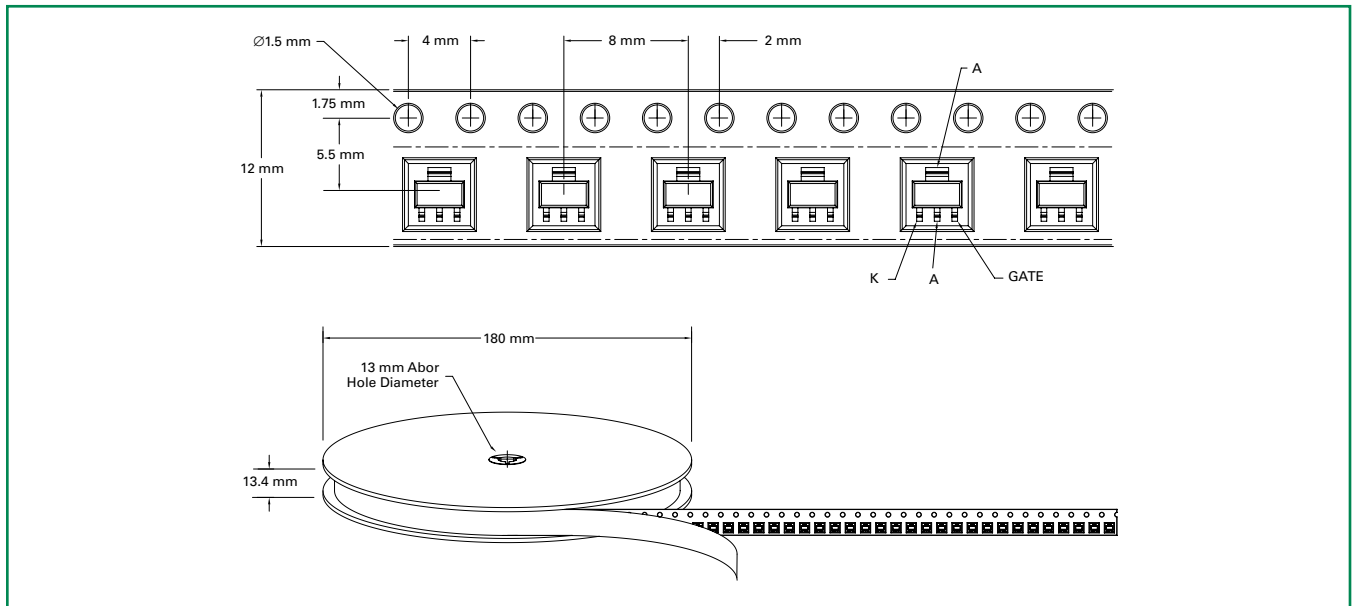
SOT-89 Reel Pack (RP) Specifications



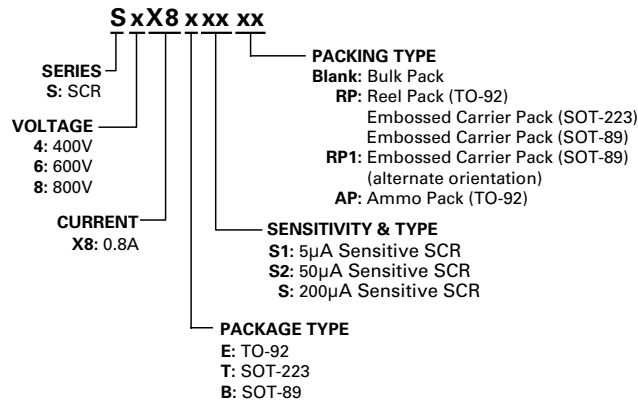
SOT-89 Reel Pack (RP1) Specifications



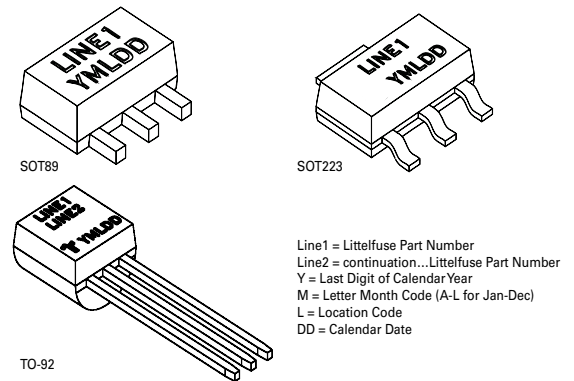
SOT-223 Reel Pack (RP) Specifications



Part Numbering System



Part Marking System



Mouser Electronics

Authorized Distributor

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[S4X8BSRP](#) [S4X8ES1AP](#) [S4X8TS1RP](#) [S6X8ES1AP](#) [S8X8ES1](#) [S8X8ES1AP](#) [S8X8ESAP](#) [S4X8ES2](#) [S4X8ES2AP](#)
[S4X8ES2RP](#) [S4X8TS2RP](#) [S6X8ES2](#) [S6X8ES2AP](#) [S8X8ES2](#) [S8X8ES2AP](#) [S602ES](#) [S402ESRP](#) [S602ESRP](#)
[S402ESAP](#) [S602ESAP](#) [S6X8TSRP](#) [S4X8TSRP](#) [S602TSRP](#) [S402TSRP](#) [S402ES](#) [S6X8BSRP](#) [S6X8ES1RP](#)
[S6X8ES2RP](#) [S6X8TS1RP](#) [S6X8TS2RP](#) [S8X8ESRP](#) [S8X8ES1RP](#) [S8X8ES2RP](#) [S8X8TSRP](#) [S8X8TS1RP](#)
[S8X8TS2RP](#) [S4X8BSRP1](#) [S4X8BS1RP](#) [S6X8BS1RP](#) [S6X8BS2RP](#) [S4X8BS2RP](#)